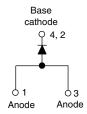


# **High Performance Schottky Rectifier, 10 A**





**TO-252AA (D-PAK)** 

PRODUCT SUMMARY					
Package TO-252AA (D-PAK)					
I <sub>F(AV)</sub>	10 A				
$V_{R}$	45 V				
V <sub>F</sub> at I <sub>F</sub>	0.53 V				
I <sub>RM</sub>	15 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
Diode variation	Single die				
E <sub>AS</sub>	20 mJ				

#### **FEATURES**

- Popular D-PAK outline
- Small foot print, surface mountable



- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### **DESCRIPTION**

The VS-10WQ045FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL CHARACTERISTICS VALUES						
I <sub>F(AV)</sub>	Rectangular waveform	10	А			
V <sub>RRM</sub>		45	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	400	Α			
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.53	V			
TJ	Range	-40 to +175	°C			

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-10WQ045FNPbF U						
Maximum DC reverse voltage	$V_{R}$	45	V			
Maximum working peak reverse voltage	$V_{RWM}$	7	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS				
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 157 °C, rectangular waveform		10	А		
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	ect. pulse Following any rated load condition and with		Α		
See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	75	^		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 3 A, L = 4.4 mH		20	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s  Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		3.0	Α		



ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
		10 A	T <sub>.1</sub> = 25 °C	0.63			
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	20 A	11=25 0	0.80	V		
See fig. 1	V FM ('')	10 A	T <sub>.1</sub> = 125 °C	0.53			
		20 A	1J = 125 C	0.71			
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	T <sub>J</sub> = 25 °C		mA		
See fig. 2	IRM (*)	$V_R = Rated V_R$	15	IIIA			
Threshold voltage	V <sub>F(TO)</sub>	T - T movimum	T. T		V		
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		22	mΩ		
Typical junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		760	pF		
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		5.0	nH		

### Note

 $<sup>^{(1)}\,</sup>$  Pulse width  $<300~\mu s,$  duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-40 to +175	°C			
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	2.0	°C/W			
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>		50	G/VV			
Approximate weight			0.3	g			
Approximate weight			0.01	OZ.			
Marking device		Case style D-PAK (similar to TO-252AA)	10WQ	045FN			

#### Note

(1) 
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink

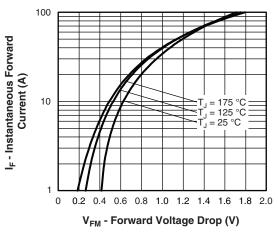


Fig. 1 - Maximum Forward Voltage Drop Characteristics

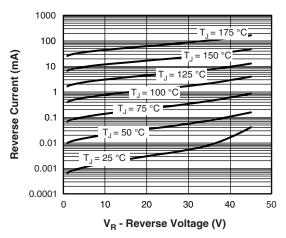


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

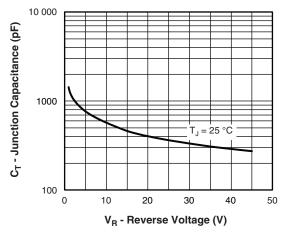


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

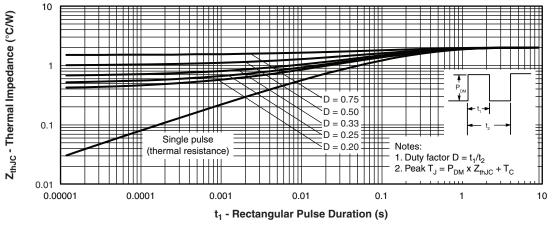


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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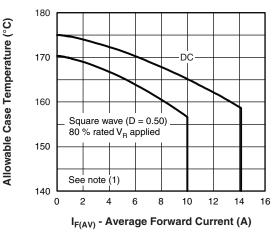


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

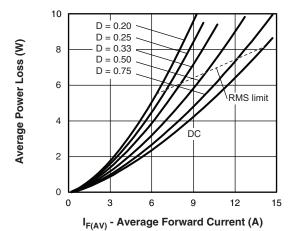


Fig. 6 - Forward Power Loss Characteristics

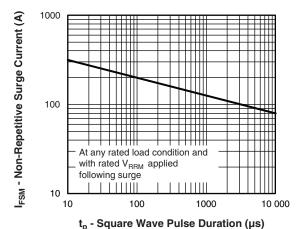


Fig. 7 - Maximum Non-Repetitive Surge Current

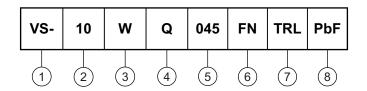
### Note

 $\begin{array}{ll} \text{(1)} \ \ \text{Formula used: } T_{C} = T_{J} \text{ - (Pd} + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_{R} \text{ (1 - D); } I_{R} \text{ at } V_{R1} = 80 \text{ \% rated } V_{R} \\ \end{array}$ 



## **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (10 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (045 = 45 V)

6 - FN = TO-252AA (D-PAK)

7 - • None = tube (50 pieces)

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

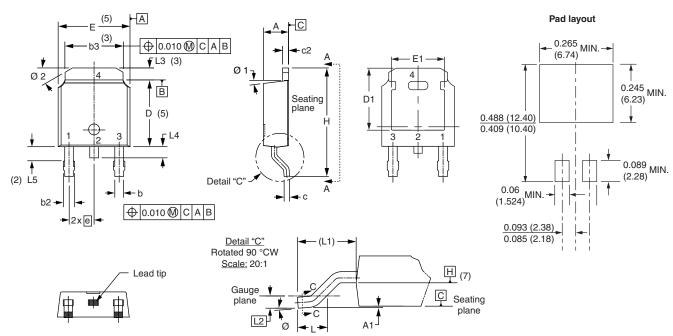
PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95016</u>					
Part marking information	www.vishay.com/doc?95059				
Packaging information	www.vishay.com/doc?95033				



# **D-PAK (TO-252AA)**

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYME		
	STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIE
	Α	2.18	2.39	0.086	0.094			е
	A1	-	0.13	-	0.005			Н
	b	0.64	0.89	0.025	0.035			L
	b2	0.76	1.14	0.030	0.045			L1
	b3	4.95	5.46	0.195	0.215	3		L2
	С	0.46	0.61	0.018	0.024			L3
	c2	0.46	0.89	0.018	0.035			L4
	D	5.97	6.22	0.235	0.245	5		L5
	D1	5.21	-	0.205	-	3		Ø
	Е	6.35	6.73	0.250	0.265	5		Ø1
	E1	4.32	-	0.170	-	3		Ø2

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108	REF.	
L2	0.51	0.51 BSC		0.020 BSC	
L3	0.89	1.27	0.035	0.050	3
L4	1	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

#### **Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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